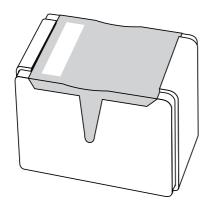
DISCRETE SEMICONDUCTORS

DATA SHEET



BAS221General purpose diode

Product specification Supersedes data of 1999 May 07 2002 May 28





General purpose diode

BAS221

FEATURES

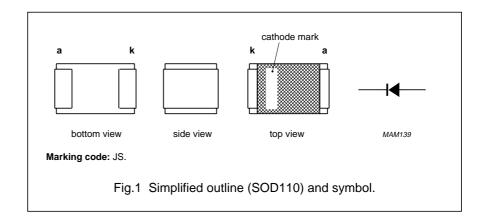
- Small ceramic SMD package
- Switching speed: max. 50 ns
- · General application
- Continuous reverse voltage: max. 200 V
- Repetitive peak reverse voltage: max. 250 V
- Repetitive peak forward current: max. 1 A.

APPLICATIONS

• General purpose switching in e.g. surface mounted circuits.

DESCRIPTION

The BAS221 is a general purpose diode fabricated in planar technology, encapsulated in a SOD110 very small ceramic SMD package.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{RRM}	repetitive peak reverse voltage		1-	250	V
V _R	continuous reverse voltage		-	200	V
I _F	continuous forward current	note 1; see Fig.2	Ī-	300	mA
I _{FRM}	repetitive peak forward current	$t_p < 0.5 \text{ ms}; \ \delta \le 0.25$	-	1	А
I _{FSM}	non-repetitive peak forward current	square wave; T _j = 25 °C prior to surge; see Fig.4			
		t = 1 μs	_	20	Α
		t = 100 μs	_	7	Α
		t = 10 ms	_	2	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	-	400	mW
T _{stg}	storage temperature		-65	+150	°C
T _i	junction temperature		-	150	°C

Note

1. Device mounted on an FR4 printed-circuit board.

General purpose diode

BAS221

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point		200	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	315	K/W

Note

1. Device mounted on an FR4 printed-circuit board.

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V _F	forward voltage	see Fig.3		
		I _F = 100 mA	1	V
		I _F = 200 mA	1.25	V
		I _F = 300 mA	1.4	V
I _R	reverse current	see Fig.5		
		V _R = 200 V	100	nA
		V _R = 200 V; T _j = 150 °C	100	μΑ
C _d	diode capacitance	f = 1 MHz; V _R = 0; see Fig.6	2	pF
t _{rr}	reverse recovery time	when switched from I_F = 30 mA to I_R = 30 mA; R_L = 100 Ω ; measured at I_R = 3 mA; see Fig.7	50	ns

General purpose diode

BAS221

GRAPHICAL DATA

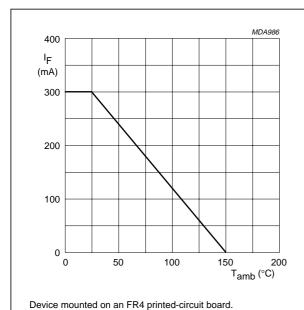
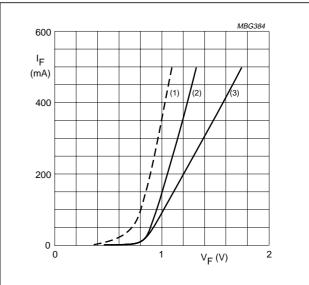


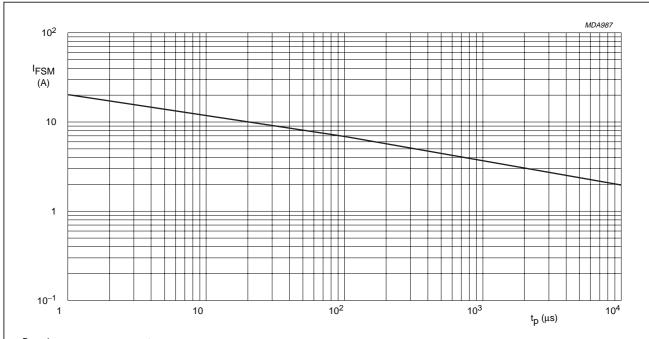
Fig.2 Maximum permissible continuous forward current as a function of ambient

temperature.



- (1) $T_i = 150$ °C; typical values.
- (2) $T_j = 25$ °C; typical values.
- (3) $T_j = 25$ °C; maximum values.

Fig.3 Forward current as a function of forward voltage.



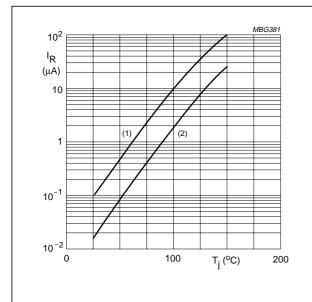
Based on square wave currents.

 T_j = 25 °C prior to surge.

Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

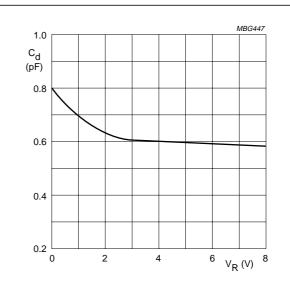
General purpose diode

BAS221



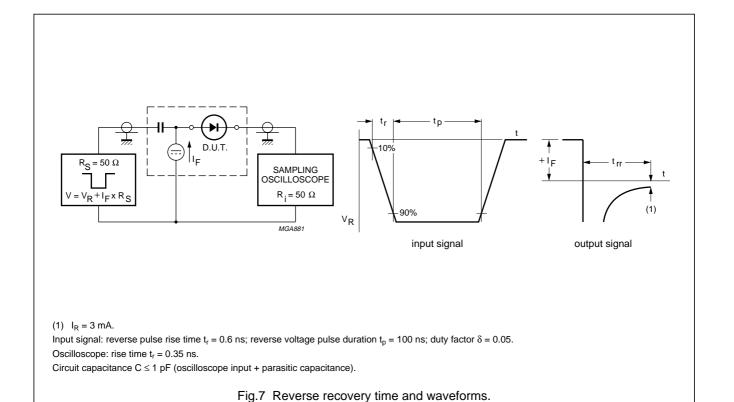
- (1) $V_R = V_{Rmax}$; maximum values.
- (2) $V_R = V_{Rmax}$; typical values.

Fig.5 Reverse current as a function of junction temperature.



 $f = 1 \text{ MHz}; T_j = 25 ^{\circ}\text{C}.$

Fig.6 Diode capacitance as a function of reverse voltage; typical values.



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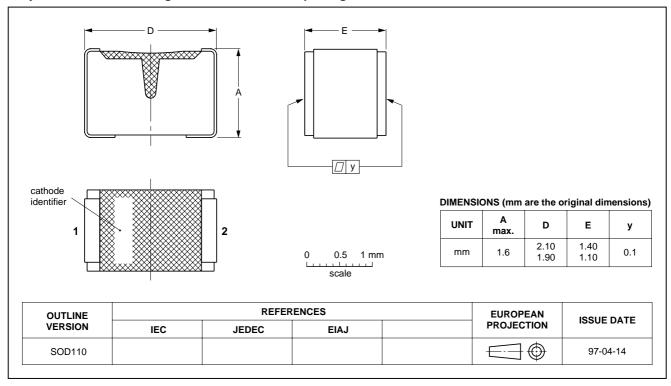
General purpose diode

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PACKAGE OUTLINE

Very small ceramic rectangular surface mounted package

SOD110



General purpose diode

BAS221

DATA SHEET STATUS

DATA SHEET STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Notes

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Printed in The Netherlands

613514/03/pp8

Date of release: 2002 May 28

Document order number: 9397 750 09731

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